8-BIT HIGH-SPEED ANALOG-TO-DIGITAL CONVERTER

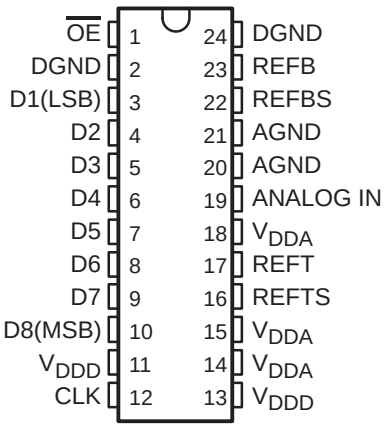
features

- **8-Bit Resolution**
- **Differential Linearity Error**
  - **±0.3 LSB Typ, ±1 LSB Max (25°C)**
  - **±1 LSB Max**
- **Integral Linearity Error**
  - **±0.6 LSB, ±0.75 LSB Max (25°C)**
  - **±1 LSB Max**
- **Maximum Conversion Rate of 40 Megasamples Per Second (MSPS) Max**
- **Internal Sample and Hold Function**
- **5-V Single Supply Operation**
- **Low Power Consumption . . . 85 mW Typ**
- **Analog Input Bandwidth . . . ≥75 MHz Typ**
- **Internal Reference Voltage Generators**

applications

- **Quadrature Amplitude Modulation (QAM) and Quadrature Phase Shift Keying (QPSK) Demodulators**
- **Digital Television**
- **Charge-Coupled Device (CCD) Scanners**
- **Video Conferencing**
- **Digital Set-Top Box**
- **Digital Down Converters**
- **High-Speed Digital Signal Processor Front End**

PW OR NS PACKAGE
(TOP VIEW)



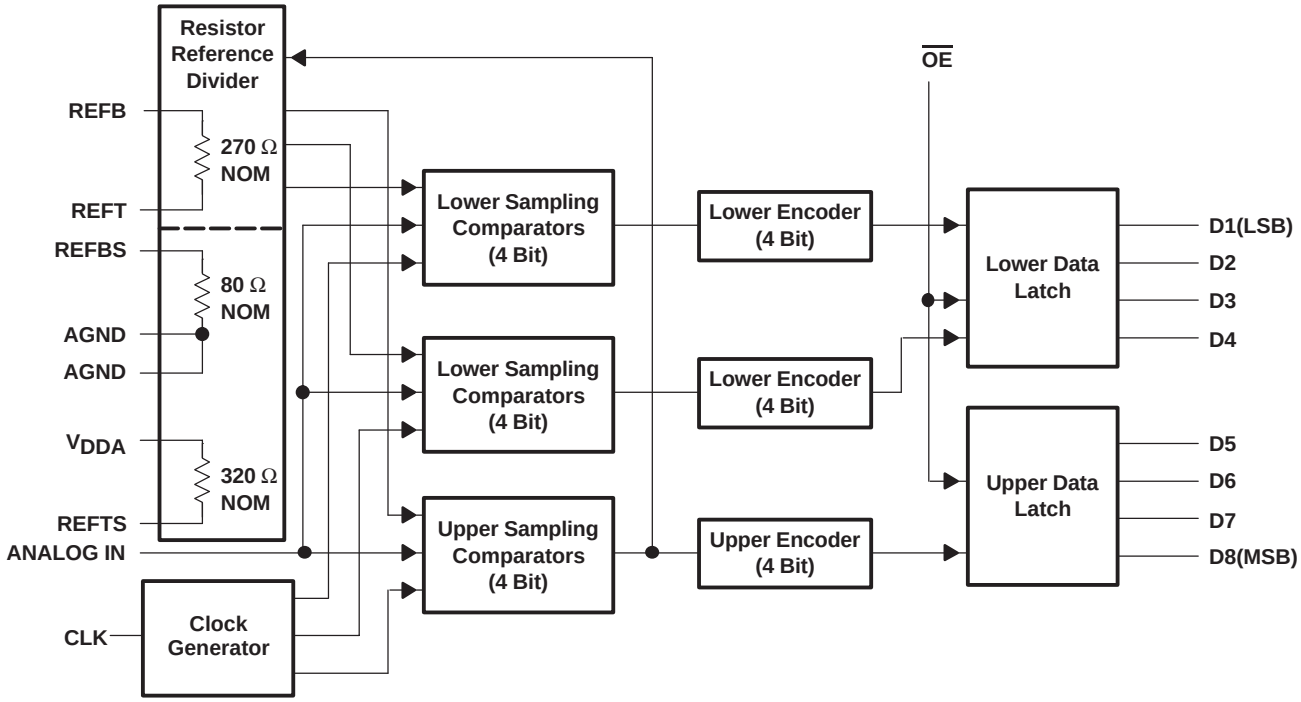
AVAILABLE OPTIONS

T_A	PACKAGE	
	TSSOP (PW)	SOP (NS)
−0°C to 70°C	TLC5540CPW	TLC5540CNSLE
−40°C to 85°C	TLC5540IPW	TLC5540INSLE

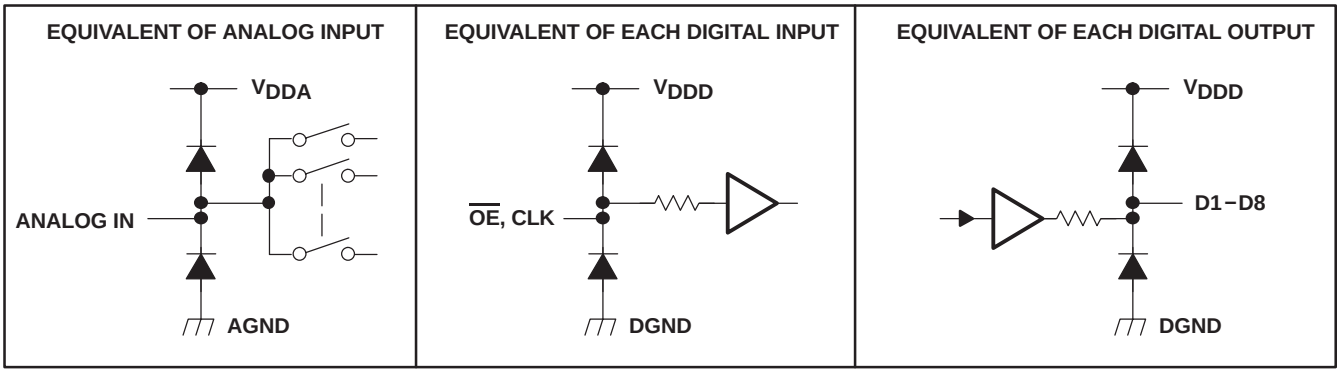
description

The TLC5540 is a high-speed, 8-bit analog-to-digital converter (ADC) that converts at sampling rates up to 40 megasamples per second (MSPS). Using a semiflash architecture and CMOS process, the TLC5540 is able to convert at high speeds while still maintaining low power consumption and cost. The analog input bandwidth of 75 MHz (typ) makes this device an excellent choice for undersampling applications. Internal resistors are provided to generate 2-V full-scale reference voltages from a 5-V supply, thereby reducing external components. The digital outputs can be placed in a high impedance mode. The TLC5540 requires only a single 5-V supply for operation.

functional block diagram



schematics of inputs and outputs



Terminal Functions

TERMINAL NAME	TERMINAL NO.	I/O	DESCRIPTION
AGND	20, 21		Analog ground
ANALOG IN	19	I	Analog input
CLK	12	I	Clock input
DGND	2, 24		Digital ground
D1−D8	3−10	O	Digital data out. D1:LSB, D8:MSB
$\overline{OE}$	1	I	Output enable. When $\overline{OE}$ = L, data is enabled. When $\overline{OE}$ = H, D1−D8 is high impedance.
V_{DDA}	14, 15, 18		Analog V_{DD}
V_{DDD}	11, 13		Digital V_{DD}
REFB	23	I	ADC reference voltage in (bottom)
REFBS	22		Reference voltage (bottom). When using the internal voltage divider to generate a nominal 2-V reference, the REFBS terminal is shorted to the REFB terminal and the REFTS terminal is shorted to the REFT terminal (see Figure 13 and Figure 14).
REFT	17	I	Reference voltage in (top)
REFTS	16		Reference voltage (top). When using the internal voltage divider to generate a nominal 2-V reference, the REFTS terminal is shorted to the REFT terminal and the REFBS terminal is shorted to the REFB terminal (see Figure 13 and Figure 14).

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V_{DDA}, V_{DDD} . . . . . 7 V
Reference voltage input range, $V_{I(REFT)}$, $V_{I(REFB)}$, $V_{I(REFBS)}$, $V_{I(REFTS)}$ . . . . . AGND to V_{DDA}
Analog input voltage range, $V_{I(ANLG)}$ . . . . . AGND to V_{DDA}
Digital input voltage range, $V_{I(DGTL)}$ . . . . . DGND to V_{DDD}
Digital output voltage range, $V_{O(DGTL)}$ . . . . . DGND to V_{DDD}
Operating free-air temperature range, T_A: TLC5540C . . . . . 0°C to 70°C
TLC5540I . . . . . −40°C to 85°C
Storage temperature range, T_{stg} . . . . . −55°C to 150°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

recommended operating conditions

		MIN	NOM	MAX	UNIT
Supply voltage	V_{DDA} − AGND	4.75	5	5.25	V
	V_{DDD} − AGND	4.75	5	5.25	
	AGND − DGND	−100	0	100	mV
Reference input voltage (top), $V_{I(REFT)}$		$V_{I(REFB)}$+1.8	$V_{I(REFB)}$+2	V_{DDA}	V
Reference input voltage (bottom), $V_{I(REFB)}$		0	0.6	$V_{I(REFT)}$−1.8	V
Analog input voltage range, $V_{I(ANLG)}$ (see Note 1)		$V_{I(REFB)}$		$V_{I(REFT)}$	V
Full scale voltage, $V_{I(REFT)} - V_{I(REFB)}$		1.8		5	V
High-level input voltage, V_{IH}		4			V
Low-level input voltage, V_{IL}				1	V
Pulse duration, clock high, $t_{w(H)}$		12.5			ns
Pulse duration, clock low, $t_{w(L)}$		12.5			ns
Operating free-air temperature, T_A	TLC5540C	0		70	°C
	TLC5540I	−40		85	°C

(1) $1.8\ V \le V_{I(REFT)} - V_{I(REFB)} < V_{DD}$

electrical characteristics at V_{DD} = 5 V, $V_{I(REFT)}$ = 2.6 V, $V_{I(REFB)}$ = 0.6 V, f_S = 40 MSPS, T_A = 25°C (unless otherwise noted)

PARAMETER		TEST CONDITIONS†			MIN	TYP	MAX	UNIT
E_L	Linearity error, integral	f_S = 40 MSPS, V_I = 0.6 V to 2.6 V	T_A = 25°C			±0.6	±1	LSB
			T_A = MIN to MAX				±1	
E_D	Linearity error, differential		T_A = 25°C			±0.3	±0.75	
			T_A = MIN to MAX				±1	
	Self bias (1), V_{RB}	Short REFB to REFBS	See Figure 13		0.57	0.61	0.65	V
	Self bias (1), V_{RT}	Short REFT to REFTS			2.47	2.63	2.80	
	Self bias (2), V_{RB}	Short REFB to AGND	See Figure 14			AGND		
	Self bias (2), V_{RT}	Short REFT to REFTS			2.18	2.29	2.4	
I_{ref}	Reference-voltage current	$V_{I(REFT)} - V_{I(REFB)}$ = 2 V			5.2	7.5	12	mA
R_{ref}	Reference-voltage resistor	Between REFT and REFB terminals			165	270	350	Ω
C_i	Analog input capacitance	$V_{I(ANLG)}$ = 1.5 V + 0.07 V_{rms}				4		pF
E_{ZS}	Zero-scale error	$V_{I(REFT)} - V_{I(REFB)}$ = 2 V			−18	−43	−68	mV
E_{FS}	Full-scale error				−25	0	25	
I_{IH}	High-level input current	V_{DD} = 5.25 V,	$V_{IH} = V_{DD}$				5	µA
I_{IL}	Low-level input current	V_{DD} = 5.25 V,	V_{IL} = 0				5	
I_{OH}	High-level output current	$\overline{OE}$ = GND,	V_{DD} = 4.75 V,	$V_{OH} = V_{DD}$ − 0.5 V	−1.5			mA
I_{OL}	Low-level output current	$\overline{OE}$ = GND,	V_{DD} = 4.75 V,	V_{OL} = 0.4 V	2.5			
$I_{OZH(lkg)}$	High-level high-impedance-state output leakage current	$\overline{OE} = V_{DD}$,	V_{DD} = 5.25,	$V_{OH} = V_{DD}$			16	µA
$I_{OZL(lkg)}$	Low-level high-impedance-state output leakage current	$\overline{OE} = V_{DD}$,	V_{DD} = 4.75,	V_{OL} = 0			16	
I_{DD}	Supply current	f_S = 40 MSPS, $C_L \leq$ 25 pF, NTSC‡ ramp wave input, See Note 1				17	27	mA

† Conditions marked MIN or MAX are as stated in recommended operating conditions.

‡ National Television System Committee

(1) Supply current specification does not include I_{ref}.

operating characteristics at V_{DD} = 5 V, V_{RT} = 2.6 V, V_{RB} = 0.6 V, f_S = 40 MSPS, T_A = 25°C (unless otherwise noted)

PARAMETER		TEST CONDITIONS†		MIN	TYP	MAX	UNIT
f_S	Maximum conversion rate	T_A = MIN to MAX		40			MSPS
f_S	Minimum conversion rate	T_A = MIN to MAX			5		MSPS
BW	Analog input full-power bandwidth	At − 3 dB, $V_{I(ANLG)}$ = 2 V_{pp}			75		MHz
t_{pd}	Delay time, digital output	C_L ≤ 10 pF (see Note 2)			9	15	ns
t_{PHZ}	Disable time, output high to Hi-Z	C_L ≤ 15 pF,	I_{OH} = −4.5 mA			20	ns
t_{PLZ}	Disable time, output low to Hi-Z	C_L ≤ 15 pF,	I_{OL} = 5 mA			20	ns
t_{PZH}	Enable time, Hi-Z to output high	C_L ≤ 15 pF,	I_{OH} = −4.5 mA			15	ns
t_{PZL}	Enable time, Hi-Z to output low	C_L ≤ 15 pF,	I_{OL} = 5 mA			15	ns
	Differential gain	NTSC 40 IRE‡ modulation wave, f_S = 14.3 MSPS			1%		
	Differential phase				0.7		degrees
t_{AJ}	Aperture jitter time				30		ps
$t_{d(s)}$	Sampling delay time				4		ns
SNR	Signal-to-noise ratio	f_S = 20 MSPS	f_I = 1 MHz		47		dB
			f_I = 3 MHz	44	47		
			f_I = 6 MHz		46		
			f_I = 10 MHz		45		
		f_S = 40 MSPS	f_I = 3 MHz		45.2		
			f_I = 6 MHz	42	44		
			f_I = 10 MHz		42		
ENOB	Effective number of bits	f_S = 20 MSPS	f_I = 1 MHz		7.64		Bits
			f_I = 3 MHz		7.61		
			f_I = 6 MHz		7.47		
			f_I = 10 MHz		7.16		
		f_S = 40 MSPS	f_I = 3 MHz		7		
			f_I = 6 MHz		6.8		
THD	Total harmonic distortion	f_S = 20 MSPS	f_I = 1 MHz		43		dBc
			f_I = 3 MHz	35	42		
			f_I = 6 MHz		41		
			f_I = 10 MHz		38		
		f_S = 40 MSPS	f_I = 3 MHz		40		
			f_I = 6 MHz		38		
	Spurious-free dynamic range	f_S = 20 MSPS	f_I = 3 MHz	41	46		dBc
		f_S = 40 MSPS			42		

† Conditions marked MIN or MAX are as stated in recommended operating conditions.
‡ Institute of Radio Engineers
(2) C_L includes probe and jig capacitance.

PARAMETER MEASUREMENT INFORMATION

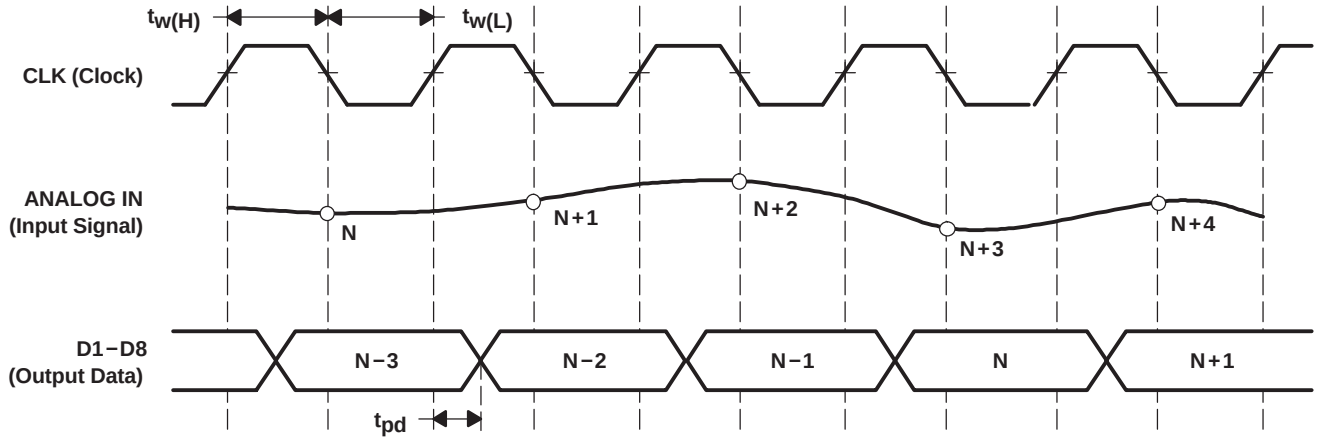


Figure 1. I/O Timing Diagram

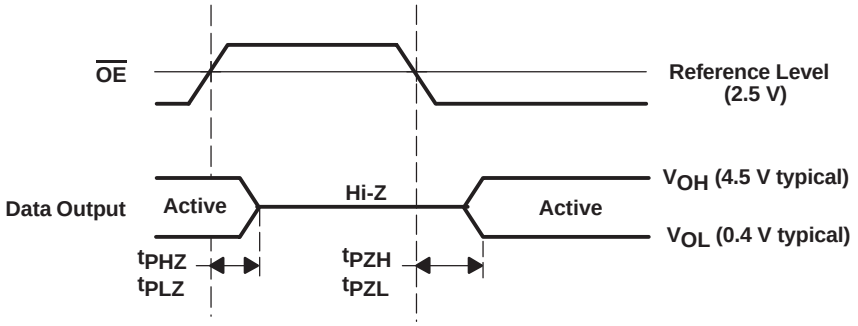


Figure 2. I/O Timing Diagram

TYPICAL CHARACTERISTICS

POWER DISSIPATION vs SAMPLING FREQUENCY

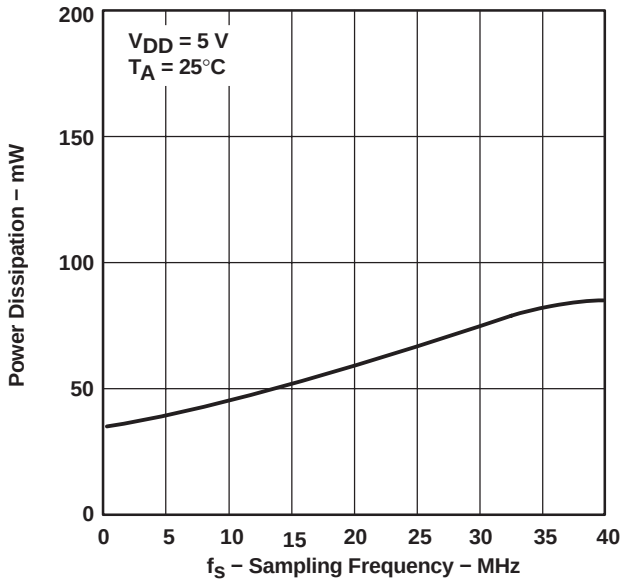


Figure 3

ANALOG INPUT BANDWIDTH

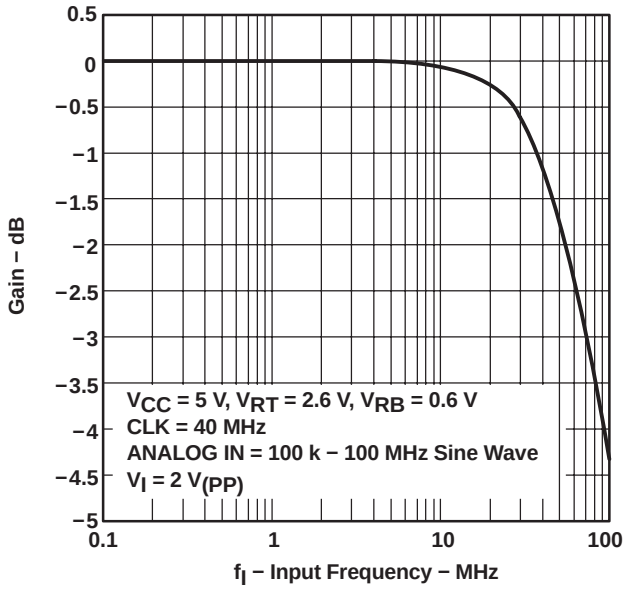


Figure 4

EFFECTIVE NUMBER OF BITS vs INPUT FREQUENCY

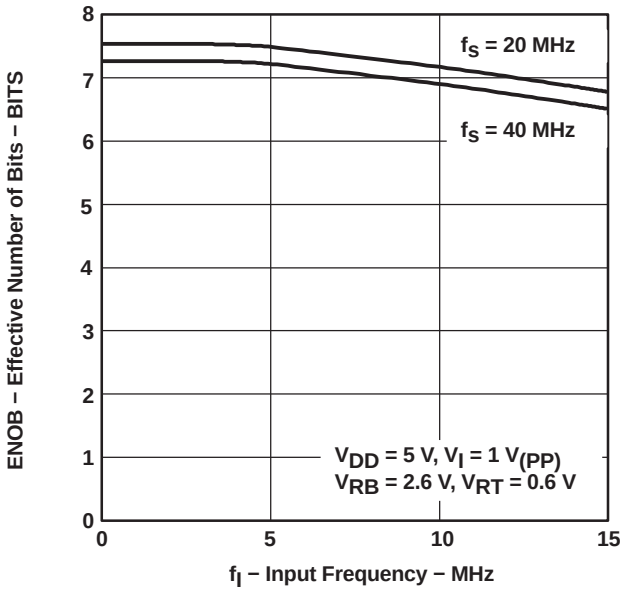


Figure 5

SIGNAL-TO-NOISE RATIO vs INPUT FREQUENCY

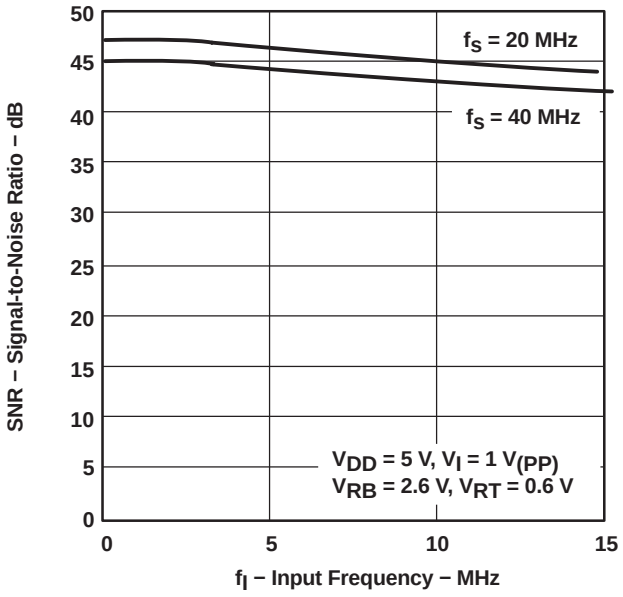


Figure 6

TYPICAL CHARACTERISTICS

DIFFERENTIAL NONLINEARITY

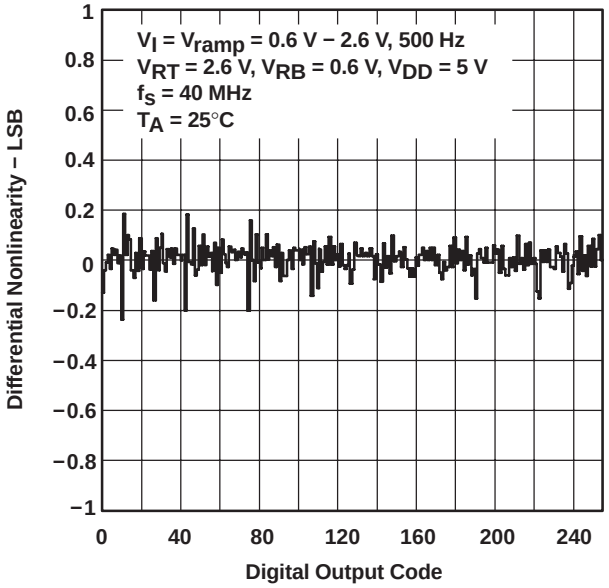


Figure 7

EFFECTIVE NUMBER OF BITS
vs
AMBIENT TEMPERATURE

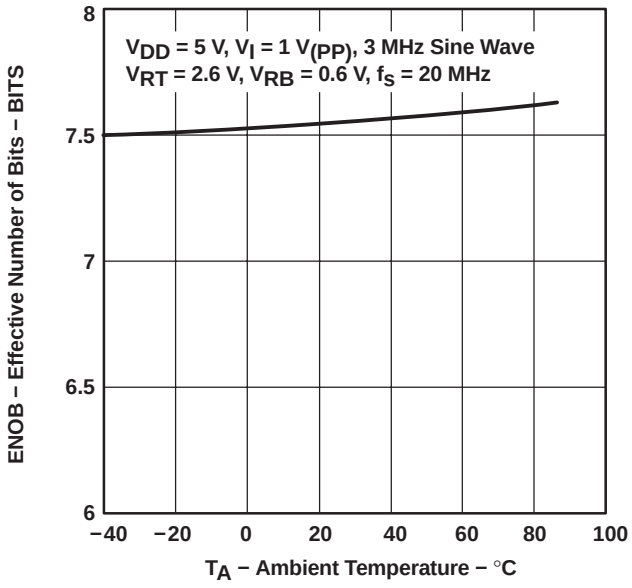


Figure 8

INTEGRAL NONLINEARITY

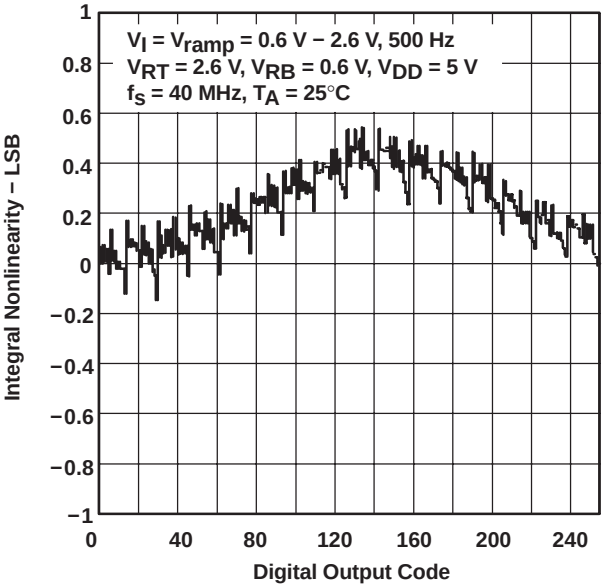


Figure 9

FFT SPECTRUM

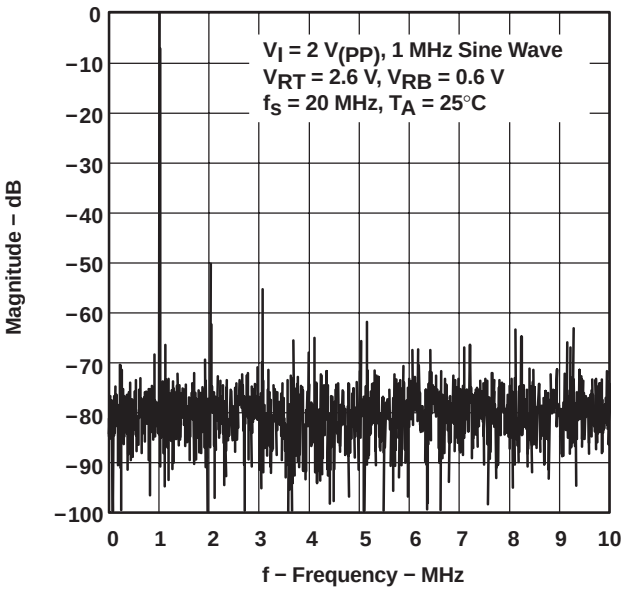


Figure 10

APPLICATION INFORMATION

grounding and power supply considerations

A signal ground is a low-impedance path for current to return to the source. Inside the TLC5540 A/D converter, the analog ground and digital ground are connected to each other through the substrate, which has a very small resistance (~30 Ω) to prevent internal latch-up. For this reason, it is strongly recommended that a printed circuit board (PCB) of at least 4 layers be used with the TLC5540 and the converter DGND and AGND pins be connected directly to the analog ground plane to avoid a ground loop. Figure 11 shows the recommended decoupling and grounding scheme for laying out a multilayer PC board with the TLC5540. This scheme ensures that the impedance connection between AGND and DGND is minimized so that their potential difference is negligible and noise source caused by digital switching current is eliminated.

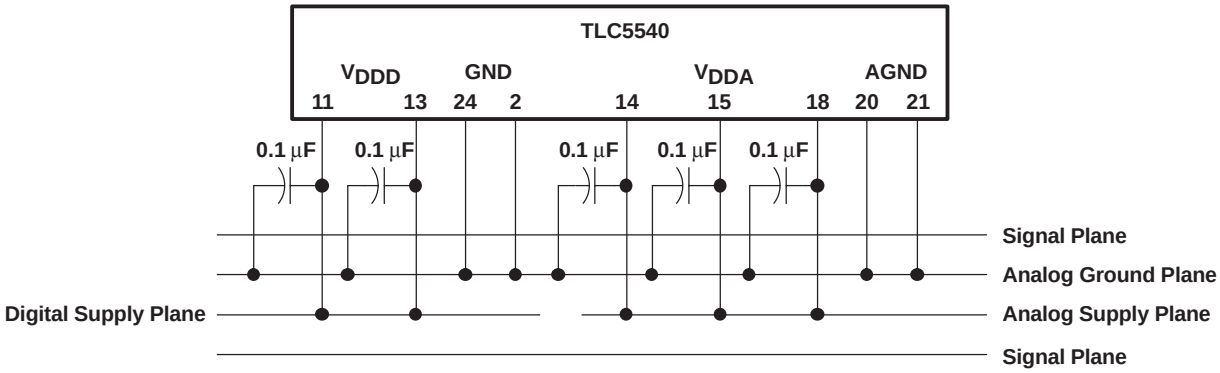


Figure 11. AV_{DD}, DV_{DD}, AGND, and DGND Connections

printed circuit board (PCB) layout considerations

When designing a circuit that includes high-speed digital and precision analog signals such as a high speed ADC, PCB layout is a key component to achieving the desired performance. The following recommendations should be considered during the prototyping and PCB design phase:

- Separate analog and digital circuitry physically to help eliminate capacitive coupling and crosstalk. When separate analog and digital ground planes are used, the digital ground and power planes should be several layers from the analog signals and power plane to avoid capacitive coupling.
- Full ground planes should be used. Do not use individual etches to return analog and digital currents or partial ground planes. For prototyping, breadboards should be constructed with copper clad boards to maximize ground plane.
- The conversion clock, CLK, should be terminated properly to reduce overshoot and ringing. Any jitter on the conversion clock degrades ADC performance. A high-speed CMOS buffer such as a 74ACT04 or 74AC04 positioned close to the CLK terminal can improve performance.
- Minimize all etch runs as much as possible by placing components very close together. It also proves beneficial to place the ADC in a corner of the PCB nearest to the I/O connector analog terminals.
- It is recommended to place the digital output data latch (if used) as close to the TLC5540 as possible to minimize capacitive loading. If D0 through D7 must drive large capacitive loads, internal ADC noise may be experienced.

PRINCIPLES OF OPERATION

functional description

The TLC5540 uses a modified semiflash architecture as shown in the functional block diagram. The four most significant bits (MSBs) of every output conversion result are produced by the upper comparator block CB1. The four least significant bits (LSBs) of each alternate output conversion result are produced by the lower comparator blocks CB-A and CB-B in turn (see Figure 12).

The reference voltage that is applied to the lower comparator resistor string is one sixteenth of the amplitude of the refence applied to the upper comparator resistor string. The sampling comparators of the lower comparator block require more time to sample the lower voltages of the reference and residual input voltage. By applying the residual input voltage to alternate lower comparator blocks, each comparator block has twice as much time to sample and convert as would be the case if only one lower comparator block were used.

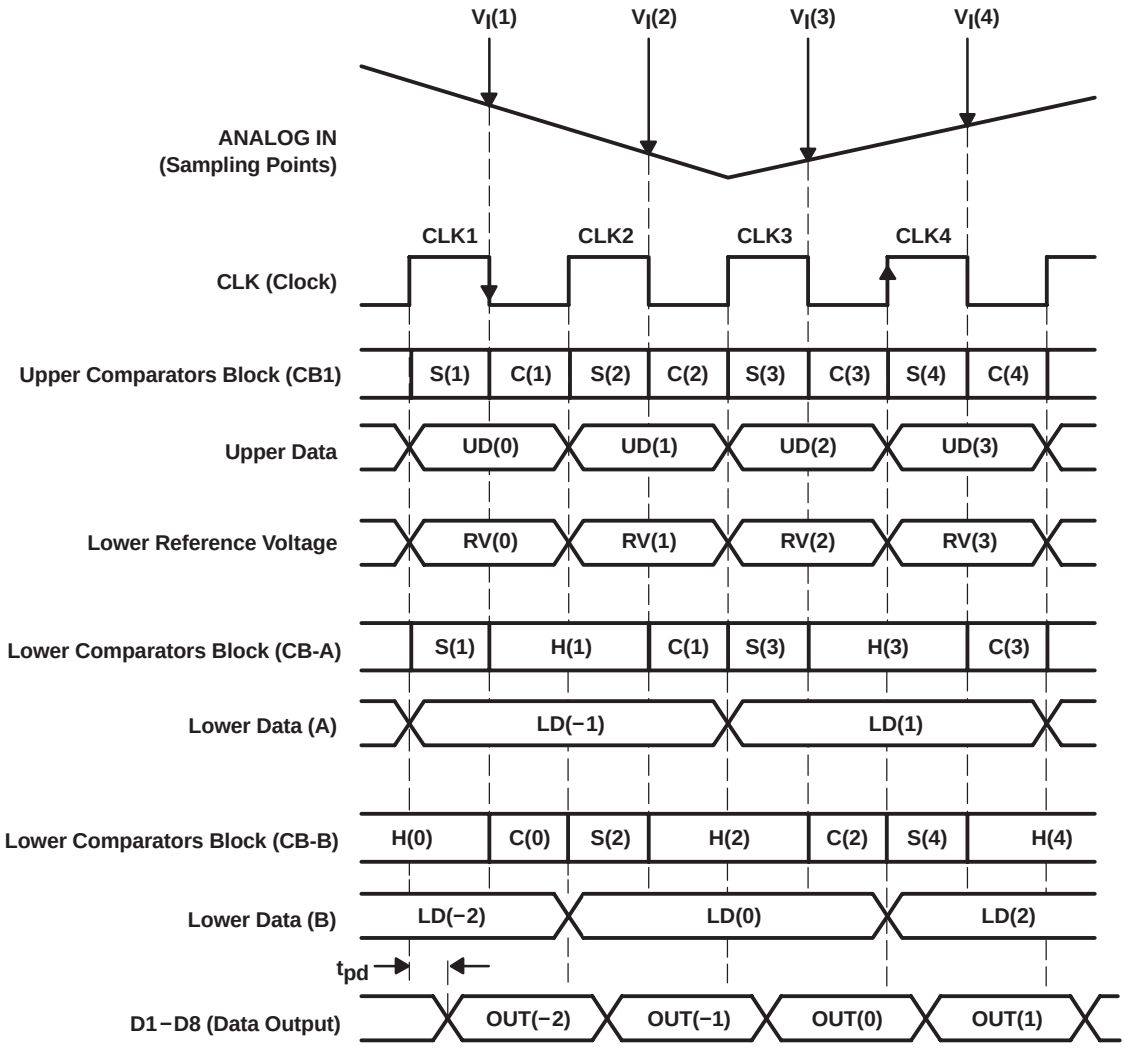


Figure 12. Internal Functional Timing Diagram

This conversion scheme, which reduces the required sampling comparators by 30 percent compared to standard semiflash architectures, achieves significantly higher sample rates than the conventional semiflash conversion method.

PRINCIPLES OF OPERATION

functional description (continued)

The MSB comparator block converts on the falling edge of each applied clock cycle. The LSB comparator blocks CB-A and CB-B convert on the falling edges of the first and second following clock cycles, respectively. The timing diagram of the conversion algorithm is shown in Figure 12.

analog input operation

The analog input stage to the TLC5540 is a chopper-stabilized comparator and is equivalently shown below:

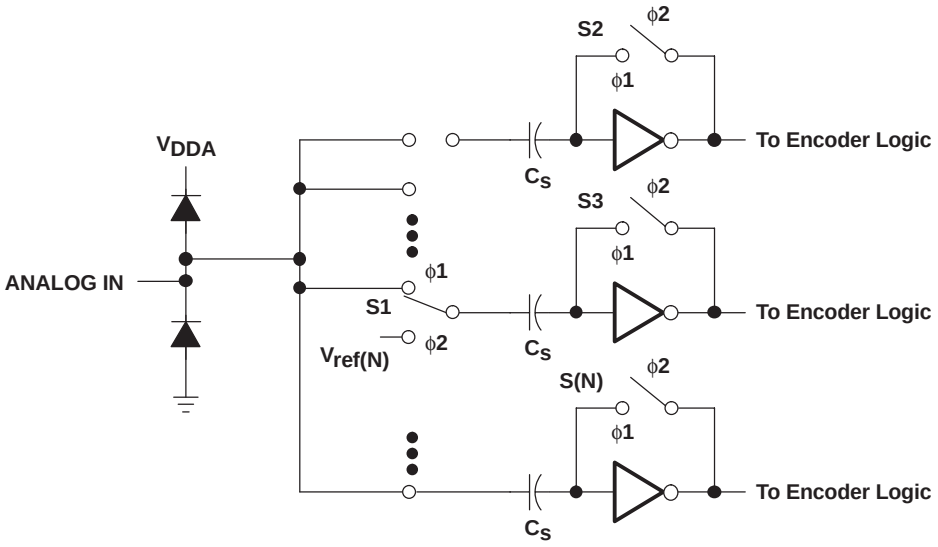


Figure 13. External Connections for Using the Internal Reference Resistor Divider

Figure 13 depicts the analog input for the TLC5540. The switches shown are controlled by two internal clocks, ϕ1 and ϕ2. These are nonoverlapping clocks that are generated from the CLK input. During the sampling period, ϕ1, S1 is closed and the input signal is applied to one side of the sampling capacitor, C_S. Also during the sampling period, S2 through S(N) are closed. This sets the comparator input to approximately 2.5 V. The delta voltage is developed across C_S. During the comparison phase, ϕ2, S1 is switched to the appropriate reference voltage for the bit value N. S2 is opened and $V_{ref(N)} - VC_S$ toggles the comparator output to the appropriate digital 1 or 0. The small resistance values for the switch, S1, and small value of the sampling capacitor combine to produce the wide analog input bandwidth of the TLC5540. The source impedance driving the analog input of the TLC5540 should be less than 100 Ω across the range of input frequency spectrum.

reference inputs − REFB, REFT, REFBS, REFTS

The range of analog inputs that can be converted are determined by REFB and REFT, REFT being the maximum reference voltage and REFB being the minimum reference voltage. The TLC5540 is tested with REFT = 2.6 V and REFB = 0.6 V producing a 2-V full-scale range. The TLC5540 can operate with REFT − REFB = 5 V, but the power dissipation in the reference resistor increases significantly (93 mW nominally). It is recommended that a 0.1 μF capacitor be attached to REFB and REFT whether using externally or internally generated voltages.

PRINCIPLES OF OPERATION

internal reference voltage conversion

Three internal resistors allow the device to generate an internal reference voltage. These resistors are brought out on terminals V_{DDA}, REFTS, REFT, REFB, REFBS, and AGND. Two different bias voltages are possible without the use of external resistors.

Internal resistors are provided to develop REFT = 2.6 V and REFB = 0.6 V (bias option one) with only two external connections. This is developed with a 3-resistor network connected to V_{DDA}. When using this feature, connect REFT to REFTS and connect REFB to REFBS. For applications where the variance associated with V_{DDA} is acceptable, this internal voltage reference saves space and cost (see Figure 14).

A second internal bias option (bias two option) is shown in Figure 15. Using this scheme REFB = AGND and REFT = 2.28 V nominal. These bias voltage options can be used to provide the values listed in the following table.

Table 1. Bias Voltage Options

BIAS OPTION	BIAS VOLTAGE		
	V_{RB}	V_{RT}	$V_{RT} - V_{RB}$
1	0.61	2.63	2.02
2	AGND	2.28	2.28

To use the internally-generated reference voltage, terminal connections should be made as shown in Figure 14 or Figure 15. The connections in Figure 14 provide the standard video 2-V reference.

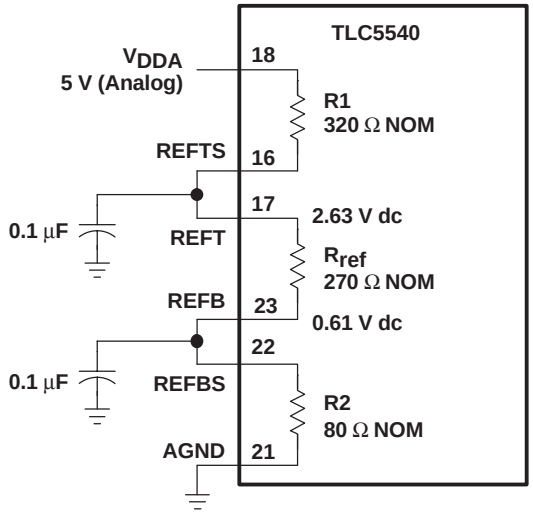


Figure 14. External Connections Using the Internal Bias One Option

PRINCIPLES OF OPERATION

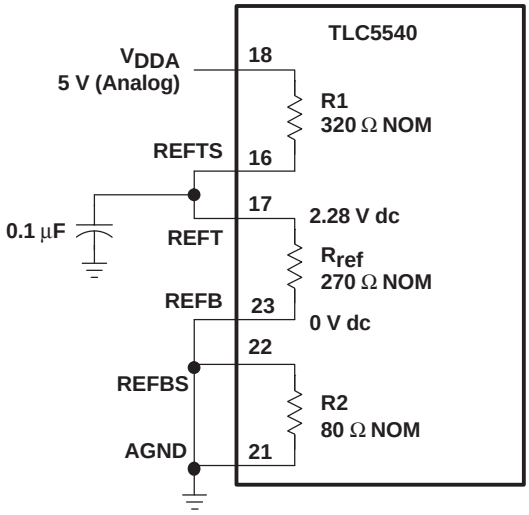


Figure 15. External Connections Using the Internal Bias Two Option

functional operation

Table 2 shows the TLC5540 functions.

Table 2. Functional Operation

INPUT SIGNAL VOLTAGE	STEP	DIGITAL OUTPUT CODE							
		MSB							LSB
$V_{ref(T)}$	255	1	1	1	1	1	1	1	1
•	•	•	•	•	•	•	•	•	•
•	•	•	•	•	•	•	•	•	•
•	128	1	0	0	0	0	0	0	0
•	127	0	1	1	1	1	1	1	1
•	•	•	•	•	•	•	•	•	•
•	•	•	•	•	•	•	•	•	•
$V_{ref(B)}$	0	0	0	0	0	0	0	0	0

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TLC5540CPW	ACTIVE	TSSOP	PW	24	60	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	0 to 70	P5540	Samples
TLC5540INSR	ACTIVE	SO	NS	24	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	TLC5540I	Samples
TLC5540IPW	ACTIVE	TSSOP	PW	24	60	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	Y5540	Samples
TLC5540IPWR	ACTIVE	TSSOP	PW	24	2000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	Y5540	Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

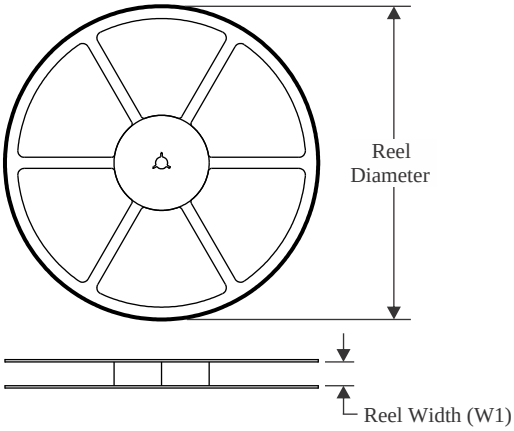
(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals.
TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

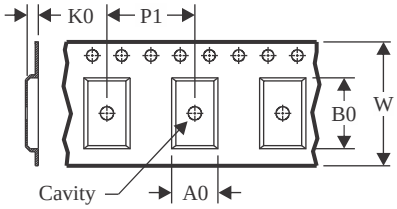
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION

REEL DIMENSIONS

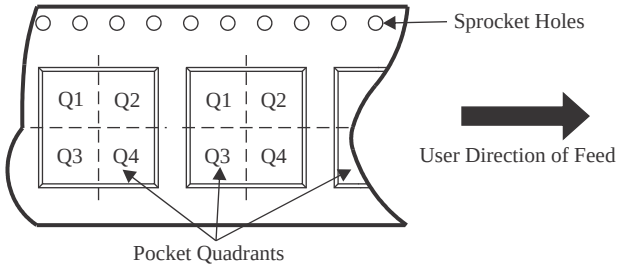


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

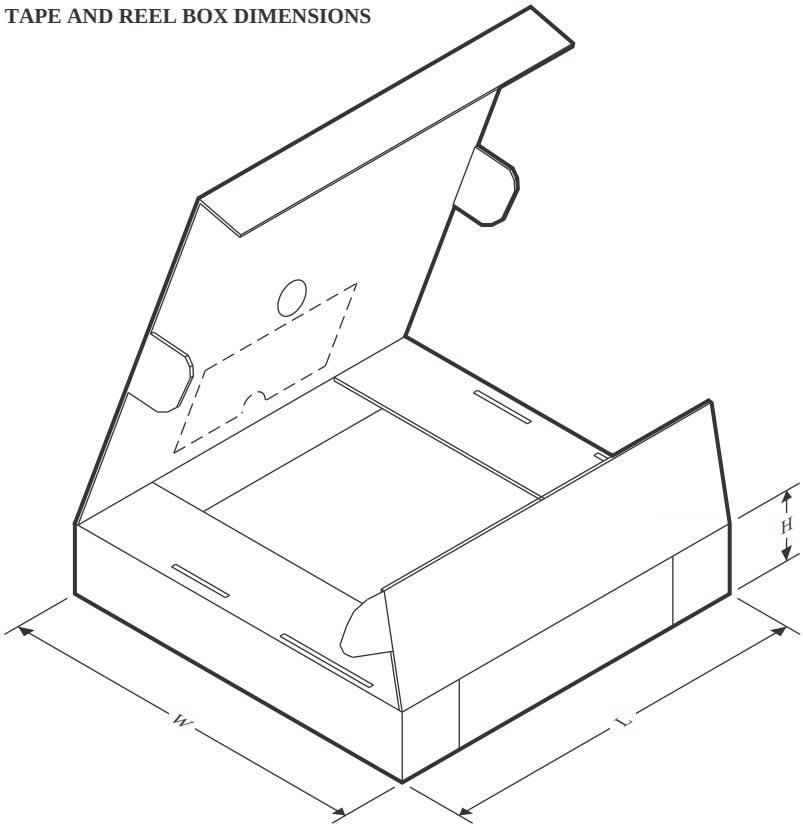
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TLC5540INSR	SO	NS	24	2000	330.0	24.4	8.5	15.3	2.6	12.0	24.0	Q1
TLC5540IPWR	TSSOP	PW	24	2000	330.0	16.4	6.95	8.3	1.6	8.0	16.0	Q1

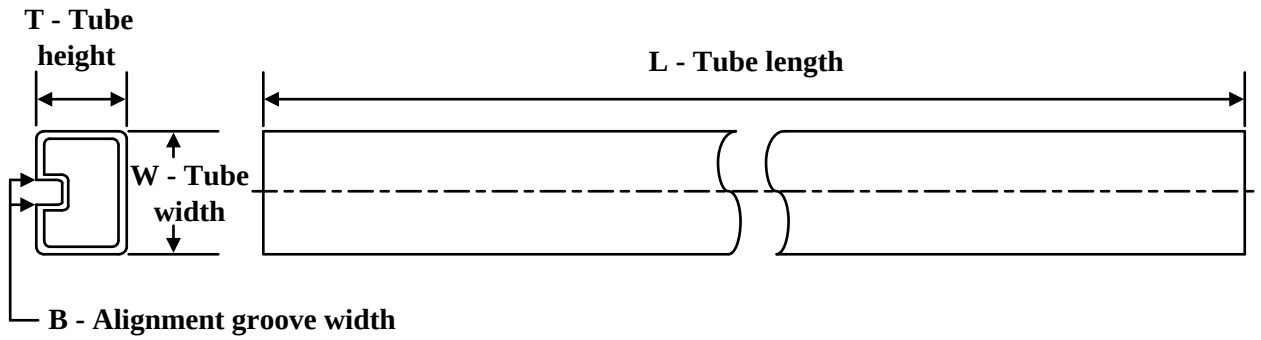
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TLC5540INSR	SO	NS	24	2000	350.0	350.0	43.0
TLC5540IPWR	TSSOP	PW	24	2000	350.0	350.0	43.0

TUBE



*All dimensions are nominal

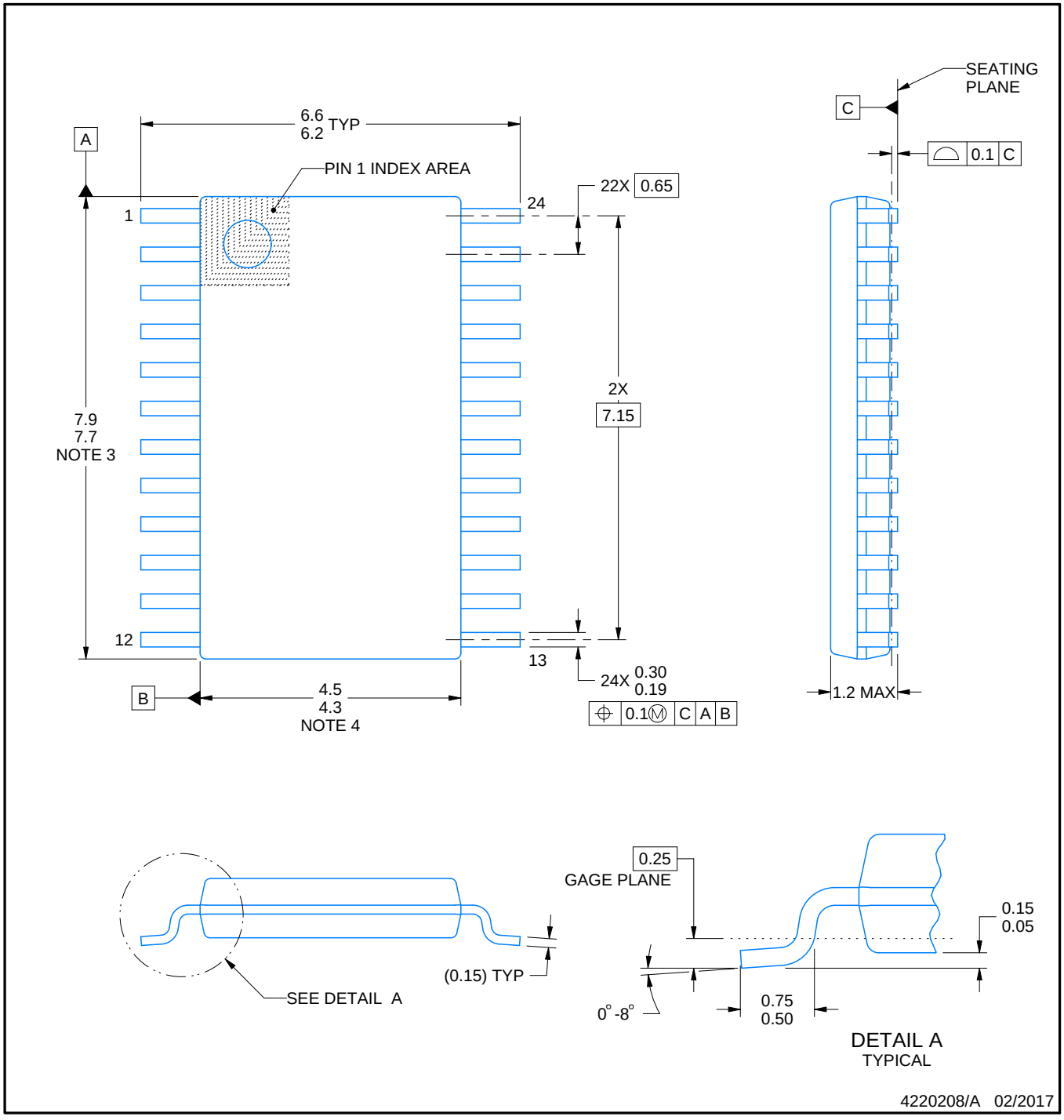
Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
TLC5540CPW	PW	TSSOP	24	60	530	10.2	3600	3.5
TLC5540IPW	PW	TSSOP	24	60	530	10.2	3600	3.5

PACKAGE OUTLINE

PW0024A

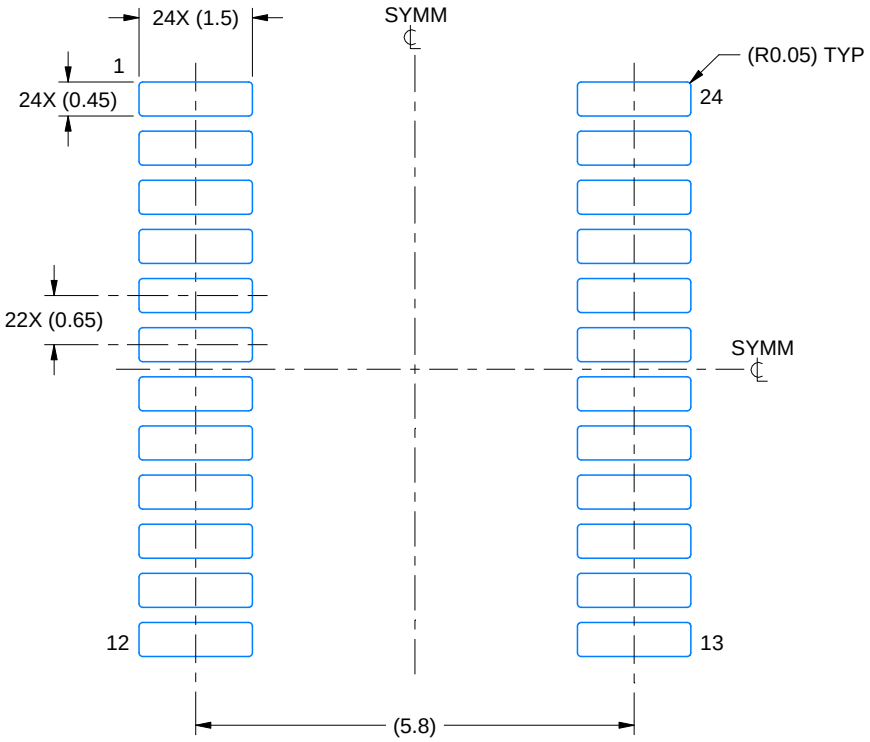
TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE

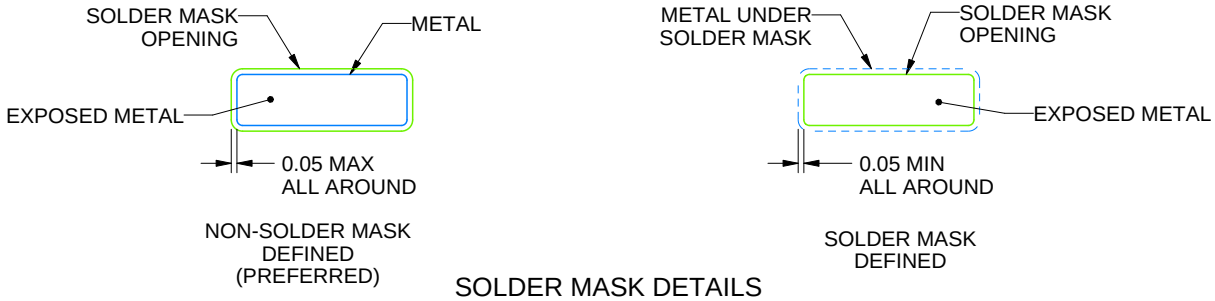


NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 10X

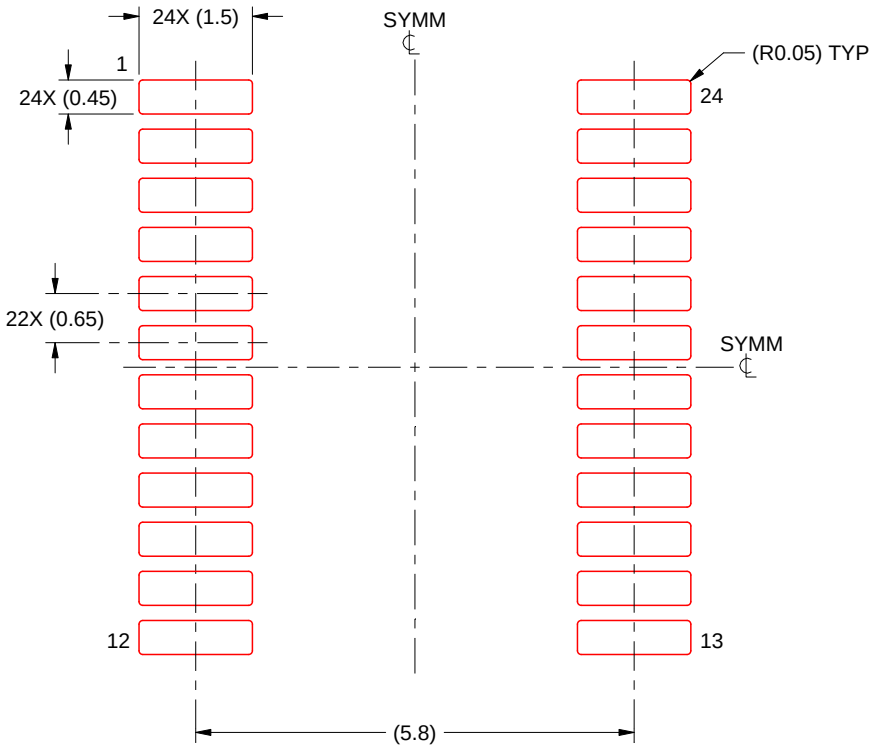


SOLDER MASK DETAILS

4220208/A 02/2017

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 10X

4220208/A 02/2017

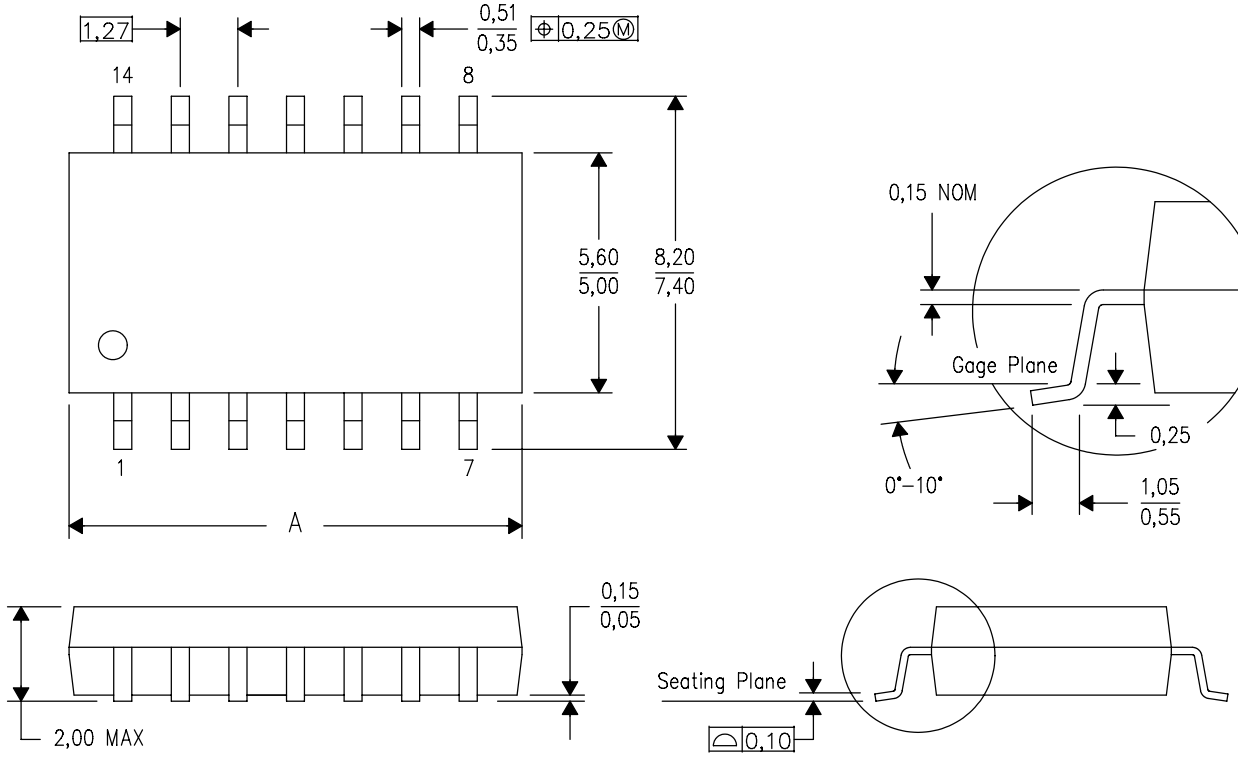
NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

MECHANICAL DATA

NS (R-PDSO-G)** **PLASTIC SMALL-OUTLINE PACKAGE**

14-PINS SHOWN



DIM \ PINS **	14	16	20	24
A MAX	10,50	10,50	12,90	15,30
A MIN	9,90	9,90	12,30	14,70

4040062/C 03/03

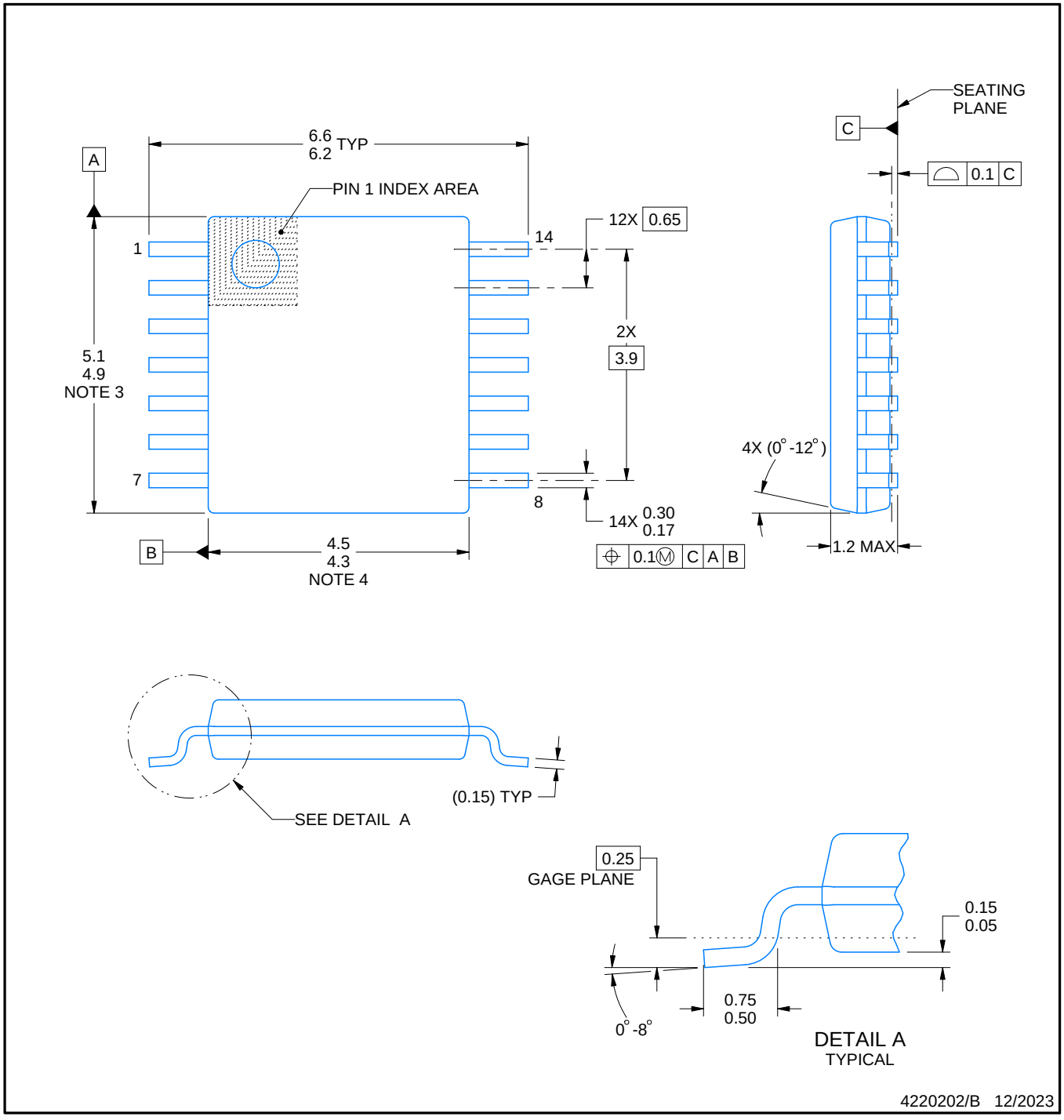
NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.

PACKAGE OUTLINE

PW0014A

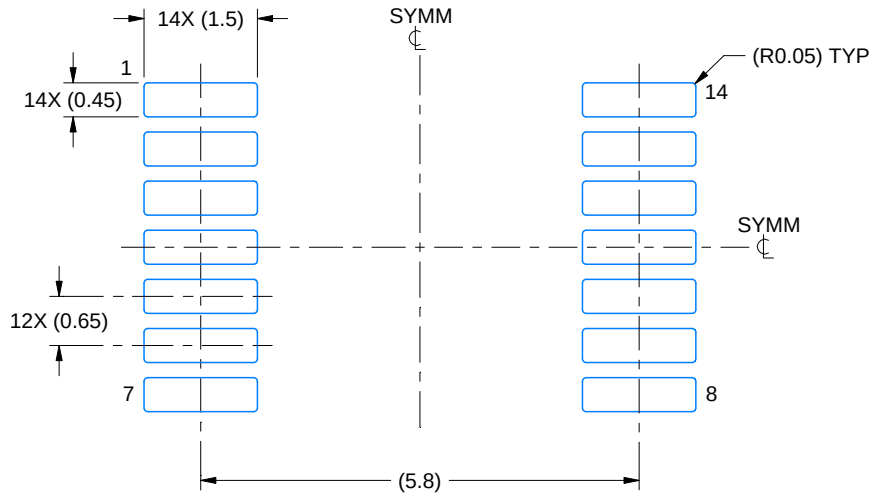
TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE

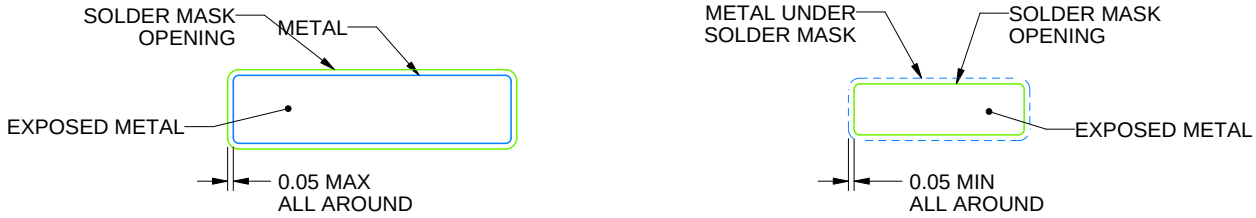


NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 10X

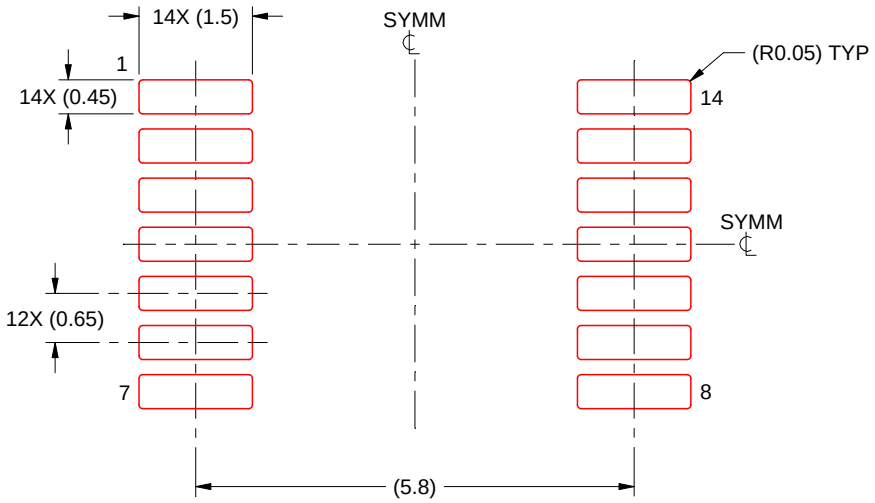


SOLDER MASK DETAILS

4220202/B 12/2023

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 10X

4220202/B 12/2023

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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